Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Metal

**Overall Length:** 

1.263 inches

## Mounting Facility Quantity:

1

## Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.437 inches

#### Thread Size:

#### 0.190 inches

## Criticality Code Justification:

Zzzy

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

40.0 repetitive peak reverse voltage

## **Current Rating Per Characteristic:**

25.00 amperes forward current, average absolute

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

## **Special Features:**

Item must comply with requirements of defense supply center columbus production standard no. Lo3744; junction pattern arrangement: pn

## **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

# Reference Number Differentiating Characteristics:

Areference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

#### Fiig:

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